NLAS3799, NLAS3799L

Dual DPDT Ultra-Low R_{ON} Switch

The NLAS3799 is an ultra−low R_{ON} DPDT and a 0.5 Ω R_{ON} DPDT analog switch. This device is designed for low operating voltage, high current switching of speaker output and earpiece for cellphone applications. It can switch a balanced stereo output. The NLAS3799 can handle a balanced microphone/speaker/ring−tone generator in a monophone mode. The device contains a break−before−make (BBM) feature.

Features

- Single Supply Operation
  1.65 to 3.6 V V_{CC}
- Maximum Breakdown Voltage: 4.6 V
- Low Static Power
- NLAS3799 Interfaces with 2.8 V Chipset
  NLAS3799L Interfaces with 1.8 V Chipset
- These are Pb−Free Devices*

Typical Applications

- Cell Phone Speaker/Microphone Switching
- Ringtone−Chip/Amplifier Switching
- Four Unbalanced (Single−Ended) Switches
- Stereo Balanced (Push−Pull) Switching

Important Information

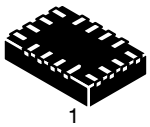
- ESD Protection:
  Human Body Model (HBM) > 8000 V
  Machine Model (MM) > 400 V
- Continuous Current Rating Through each Switch ±300 mA
- Conforms to: JEDEC MO−220, Issue H, Variation VEED−6
- Package: 1.8 x 2.6 x 0.75 mm WQFN−16 Pb−Free

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

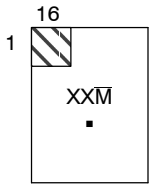
ON Semiconductor®

http://onsemi.com

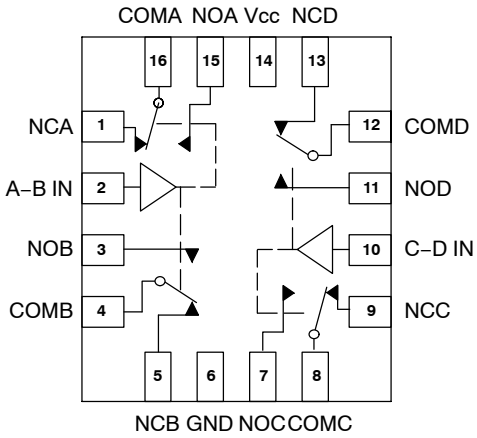
MARKING DIAGRAMS



WQFN−16
CASE 488AP



XX = Specific Device Code
AR = NLAS3799
AT = NLAS3799L
M = Date Code/Assembly Location
▪ = Pb−Free Package



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

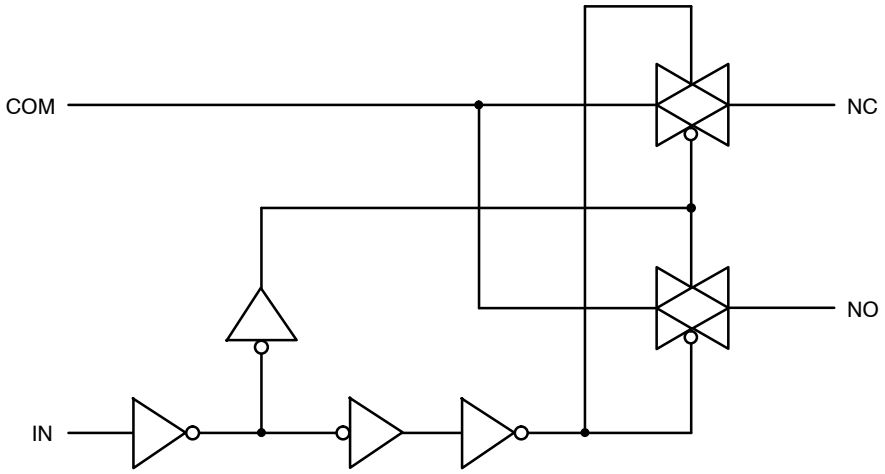


Figure 1. Input Equivalent Circuit

PIN DESCRIPTION

QFN PIN #	Symbol	Name and Function
1, 3, 5, 7, 9, 11, 13, 15	NO A−D, NC A−D	Independent Channels
2, 10	A−B IN, C−D IN	Controls
4, 8, 12, 16	COM A−D	Common Channels
6	GND	Ground (V)
14	V_{CC}	Positive Supply Voltage

TRUTH TABLE

IN	NO	NC
H	ON	OFF*
L	OFF*	ON

*High impedance.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage	−0.5 to +4.6	V
V_{IS}	Analog Input Voltage (V_{NO}, V_{NC}, or V_{COM})	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V_{IN}	Digital Select Input Voltage	$-0.5 \le V_{IN} \le +V_{CC}$	V
I_{anl1}	Continuous DC Current from COM to NC/NO	±300	mA
$I_{anl-pk1}$	Peak Current from COM to NC/NO, 10 Duty Cycle (Note 1)	±500	mA
I_{clmp}	Continuous DC Current into COM/NO/NC with Respect to V_{CC} or GND	±100	mA
T_S	Storage Temperature	−65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% OFF Duty Cycle.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		1.65	3.6	V
V_{IN}	Digital Select Input Voltage		GND	V_{CC}	V
V_{IS}	Analog Input Voltage (NC, NO, COM)		GND	V_{CC}	V
T_A	Operating Temperature Range		−40	+85	°C
t_r, t_f	Input Rise or Fall Time, IN	V_{CC} = 1.6 V – 2.7 V V_{CC} = 3.0 V – 3.6 V		20 10	ns/V

NLAS3799 DC CHARACTERISTICS – DIGITAL SECTION (Voltages Referenced to GND)

Symbol	Parameter	Condition	V_{CC}	Guaranteed Limit		Unit
				25°C	–40°C to +85°C	
V_{IH}	Minimum High–Level Input Voltage, Select Inputs		3.0 3.6	1.4 1.7	1.4 1.7	V
V_{IL}	Maximum Low–Level Input Voltage, Select Inputs		3.0 3.6	0.5 0.5	0.5 0.5	V
I_{IN}	Maximum Input Leakage Current, Select Inputs	V_{IN} = V_{CC} or GND	3.6	±0.1	±1.0	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = 3.6 V or GND	0	±0.5	±2.0	μA
I_{CC}	Maximum Quiescent Supply Current (Note 2)	Select and V_{IS} = V_{CC} or GND	1.65 to 3.6	±1.0	±2.0	μA

2. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

NLAS3799 DC ELECTRICAL CHARACTERISTICS – ANALOG SECTION

Symbol	Parameter	Condition	V_{CC}	Guaranteed Maximum Limit				Unit
				25°C		–40°C to +85°C		
				Min	Max	Min	Max	
R_{ON}	NC/NO On–Resistance (Note 3)	V_{IN} = V_{IL} or V_{IN} = V_{IH} V_{IS} = GND to V_{CC} I_{IN}I = 100 mA	3.0 3.6		0.5 0.4		0.5 0.4	Ω
R_{FLAT}	NC/NO On–Resistance Flatness (Notes 3 and 4)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	3.0 3.6		0.15 0.15		0.15 0.15	Ω
ΔR_{ON}	On–Resistance Match Between Channels (Notes 3 and 5)	V_{IS} = 1.5 V; I_{COM} = 100 mA V_{IS} = 1.8 V; I_{COM} = 100 mA	3.0 3.6		0.05 0.05		0.05 0.05	Ω
$I_{NC(OFF)}$ $I_{NO(OFF)}$	NC or NO Off Leakage Current (Note 3)	V_{IN} = V_{IL} or V_{IH} V_{NO} or V_{NC} = 0.3 V V_{COM} = 3.3 V	3.6	–10	10	–100	100	nA
$I_{COM(ON)}$	COM ON Leakage Current (Note 3)	V_{IN} = V_{IL} or V_{IH} V_{NO} 0.3 V or 3.3 V with V_{NC} floating or V_{NC} 0.3 V or 3.3 V with V_{NO} floating V_{COM} = 0.3 V or 3.3 V	3.6	–10	10	–100	100	nA

3. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
4. Flatness is defined as the difference between the maximum and minimum value of On–resistance as measured over the specified analog signal ranges.
5. ΔR_{ON} = $R_{ON(MAX)}$ – $R_{ON(MIN)}$ between nS2 or nS1.

NLAS3799L DC CHARACTERISTICS – DIGITAL SECTION (Voltages Referenced to GND)

Symbol	Parameter	Condition	V_{CC}	Guaranteed Limit		Unit
				25°C	–40 to +85°C	
V_{IH}	Minimum High–Level Input Voltage, Select Inputs		3.0 3.6	1.2 1.3	1.2 1.3	V
V_{IL}	Maximum Low–Level Input Voltage, Select Inputs		3.0 3.6	0.5 0.5	0.5 0.5	V
I_{IN}	Maximum Input Leakage Current, Select Inputs	V_{IN} = V_{CC} or GND	3.6	±0.1	±1.0	μA
I_{OFF}	Power Off Leakage Current	V_{IN} = 3.6 V or GND	0	±0.5	±2.0	μA
I_{CC}	Maximum Quiescent Supply Current (Note 6)	Select and V_{IS} = V_{CC} or GND	1.65 to 3.6	±10	±20	μA

6. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.

NLAS3799L DC ELECTRICAL CHARACTERISTICS – ANALOG SECTION

Symbol	Parameter	Condition	V_{CC}	Guaranteed Maximum Limit				Unit
				25°C		–40°C to +85°C		
				Min	Max	Min	Max	
R_{ON}	NC/NO On–Resistance (Note 7)	V_{IN} = V_{IL} or V_{IN} = V_{IH} V_{IS} = GND to V_{CC} I_{IN}I = 100 mA	3.0 3.6		0.5 0.5		0.5 0.5	Ω
R_{FLAT}	NC/NO On–Resistance Flatness (Notes 7 and 8)	I_{COM} = 100 mA V_{IS} = 0 to V_{CC}	3.0 3.6		0.15 0.15		0.15 0.15	Ω
ΔR_{ON}	On–Resistance Match Between Channels (Notes 7 and 9)	V_{IS} = 1.5 V; I_{COM} = 100 mA V_{IS} = 1.8 V; I_{COM} = 100 mA	3.0 3.6		0.05 0.05		0.05 0.05	Ω
$I_{NC(OFF)}$ $I_{NO(OFF)}$	NC or NO Off Leakage Current (Note 7)	V_{IN} = V_{IL} or V_{IH} V_{NO} or V_{NC} = 0.3 V V_{COM} = 3.3 V	3.6	–10	10	–100	100	nA
$I_{COM(ON)}$	COM ON Leakage Current (Note 7)	V_{IN} = V_{IL} or V_{IH} V_{NO} 0.3 V or 3.3 V with V_{NC} floating or V_{NC} 0.3 V or 3.3 V with V_{NO} floating V_{COM} = 0.3 V or 3.3 V	3.6	–10	10	–100	100	nA

7. Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
8. Flatness is defined as the difference between the maximum and minimum value of On–resistance as measured over the specified analog signal ranges.
9. ΔR_{ON} = $R_{ON(MAX)}$ – $R_{ON(MIN)}$ between NC1 and NC2 or between NO1 and NO2.

NLAS3799/NLAS3799L AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

Symbol	Parameter	Test Conditions	V_{CC} (V)	V_{IS} (V)	Guaranteed Maximum Limit					Unit
					25°C			−40°C to +85°C		
					Min	Typ*	Max	Min	Max	
t_{ON}	Turn−On Time	R_L = 50 Ω, C_L = 35 pF (Figures 3 and 4)	2.3 – 3.6	1.5			50		60	ns
t_{OFF}	Turn−Off Time	R_L = 50 Ω, C_L = 35 pF (Figures 3 and 4)	2.3 – 3.6	1.5			30		40	ns
t_{BBM}	Minimum Break−Before−Make Time	V_{IS} = 3.0 R_L = 50 Ω, C_L = 35 pF (Figure 2)	3.0	1.5	2	15				ns

		Typical @ 25, V_{CC} = 3.6 V	
C_{IN}	Control Pin Input Capacitance	3.0	pF
C_{SN}	SN Port Capacitance	72	pF
C_D	D Port Capacitance When Switch is Enabled	220	pF

*Typical Characteristics are at 25°C.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

Symbol	Parameter	Condition	V_{CC} (V)	25°C	Unit
				Typical	
BW	Maximum On−Channel −3 dB Bandwidth or Minimum Frequency Response (Figure 9)	V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 3.6	19	MHz
V_{ONL}	Maximum Feed−through On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 3.6	−0.06	dB
V_{ISO}	Off−Channel Isolation	f = 100 kHz; V_{IS} = 1 V RMS; C_L = 5.0 pF V_{IN} centered between V_{CC} and GND(Figure 5)	1.65 – 3.6	−69	dB
Q	Charge Injection Select Input to Common I/O (Figure 8)	V_{IN} = V_{CC} to GND, R_{IS} = 0 Ω, C_L = 1.0 nF $Q = C_L \times \Delta V_{OUT}$ (Figure 6)	1.65 – 3.6	42	pC
THD	Total Harmonic Distortion THD + Noise (Figure 7)	F_{IS} = 20 Hz to 20 kHz, R_L = R_{gen} = 600 Ω, C_L = 50 pF V_{IS} = 2 V_{PP}	3.0	0.11	%
VCT	Channel−to−Channel Crosstalk (Figure 10)	f = 100 kHz; V_{IS} = 1.0 V RMS, C_L = 5.0 pF, R_L = 50 Ω V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 3.6	−90	dB

10. Off−Channel Isolation = 20log10 (V_{COM}/V_{NO}), V_{COM} = output, V_{NO} = input to off switch.

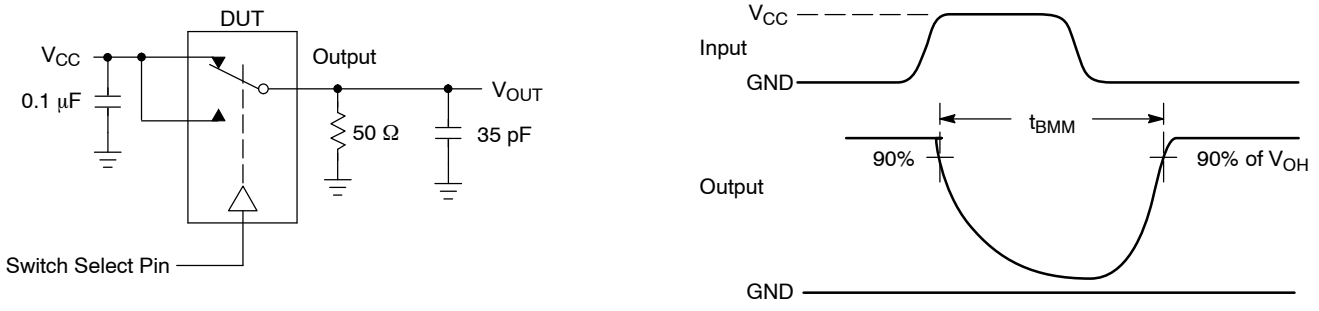


Figure 2. t_{BBM} (Time Break−Before−Make)

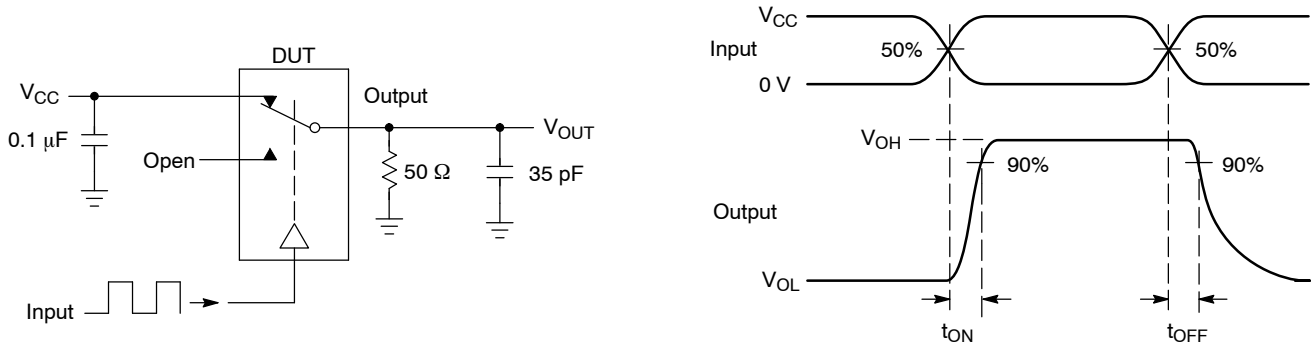


Figure 3. t_{ON}/t_{OFF}

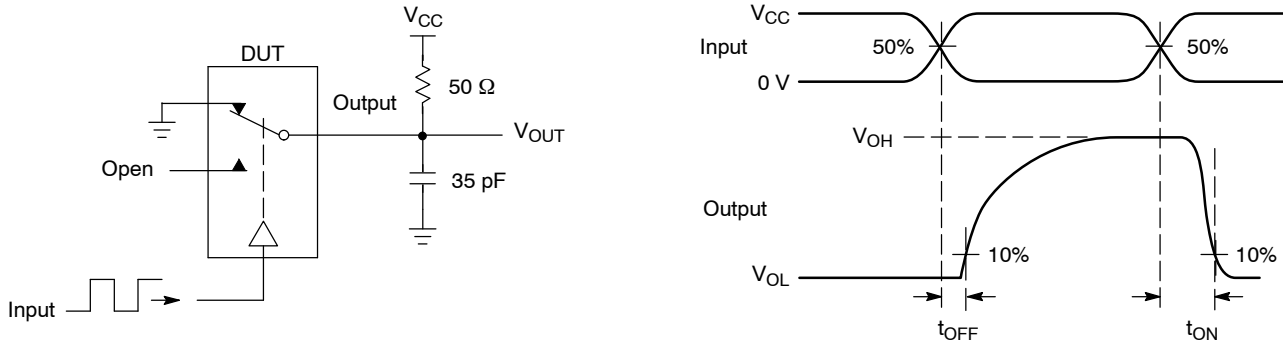
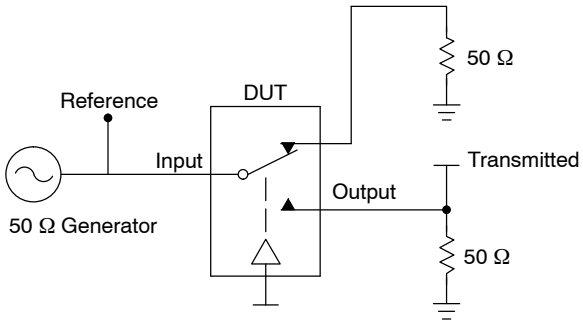


Figure 4. t_{ON}/t_{OFF}



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. V_{ISO}, Bandwidth and V_{ONL} are independent of the input signal direction.

V_{ISO} = Off Channel Isolation = 20 Log $\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz

V_{ONL} = On Channel Loss = 20 Log $\left(\frac{V_{OUT}}{V_{IN}}\right)$ for V_{IN} at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3 dB below V_{ONL}
V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 5. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

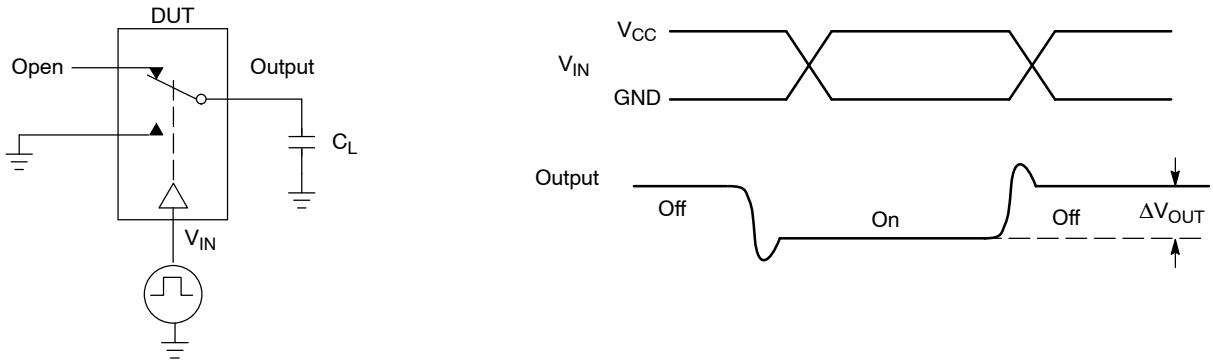


Figure 6. Charge Injection: (Q)

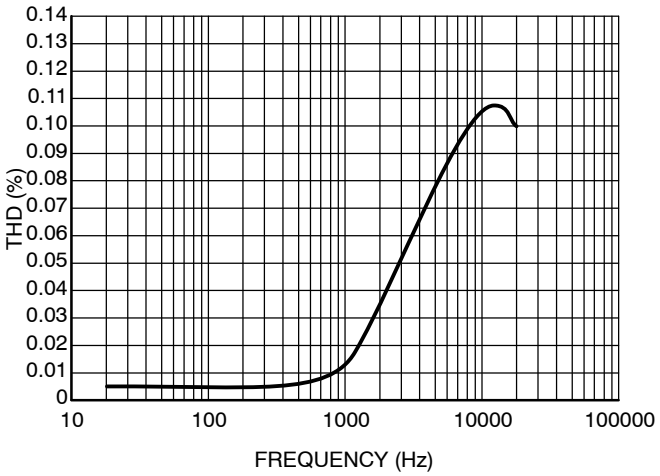


Figure 7. Total Harmonic Distortion vs. Frequency

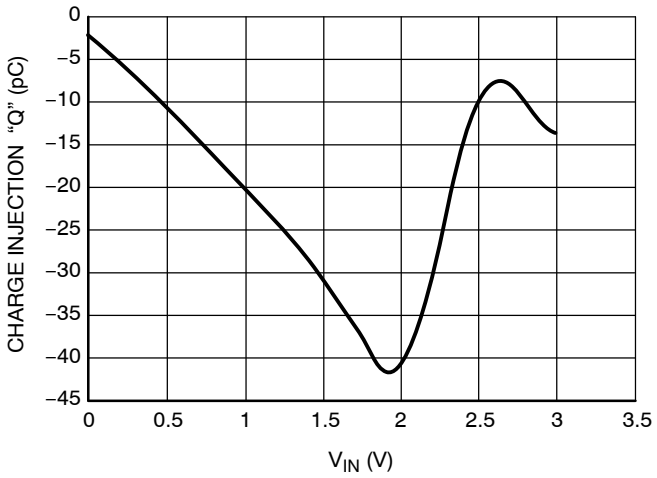


Figure 8. Charge Injection @ V_{CC} = 3.0 V

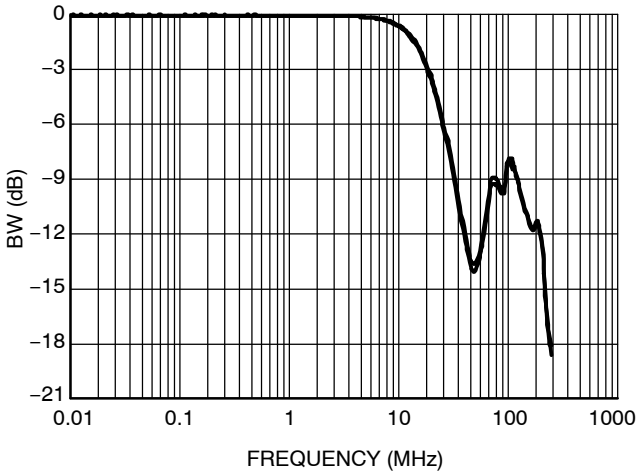


Figure 9. Bandwidth vs. Frequency

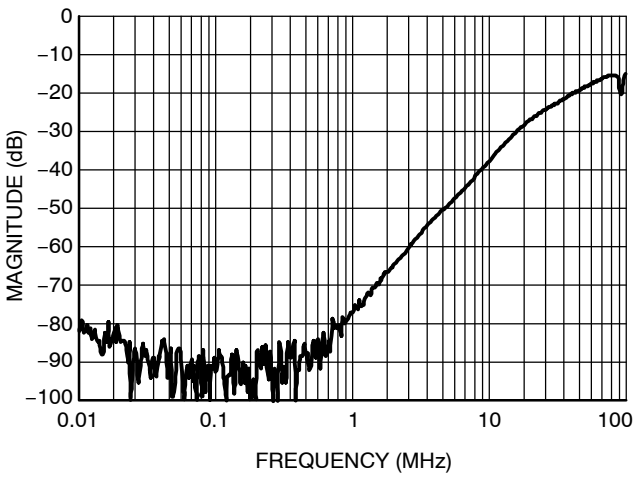


Figure 10. Cross−Talk vs. Frequency

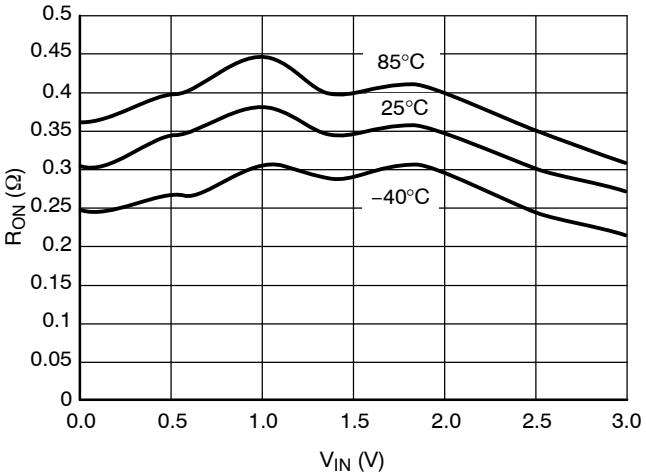


Figure 11. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 3.0 V

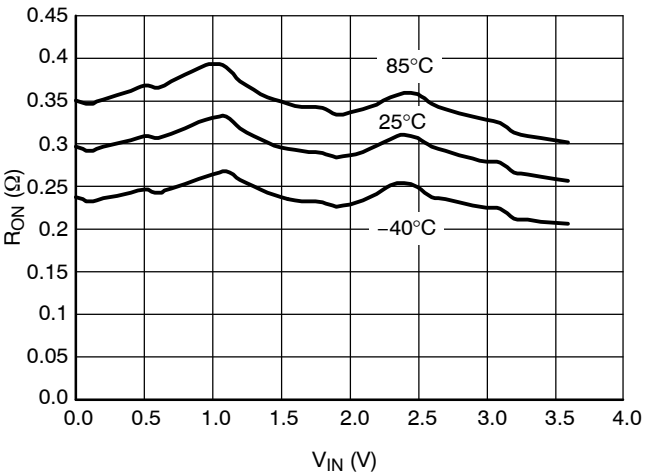


Figure 12. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 3.6 V

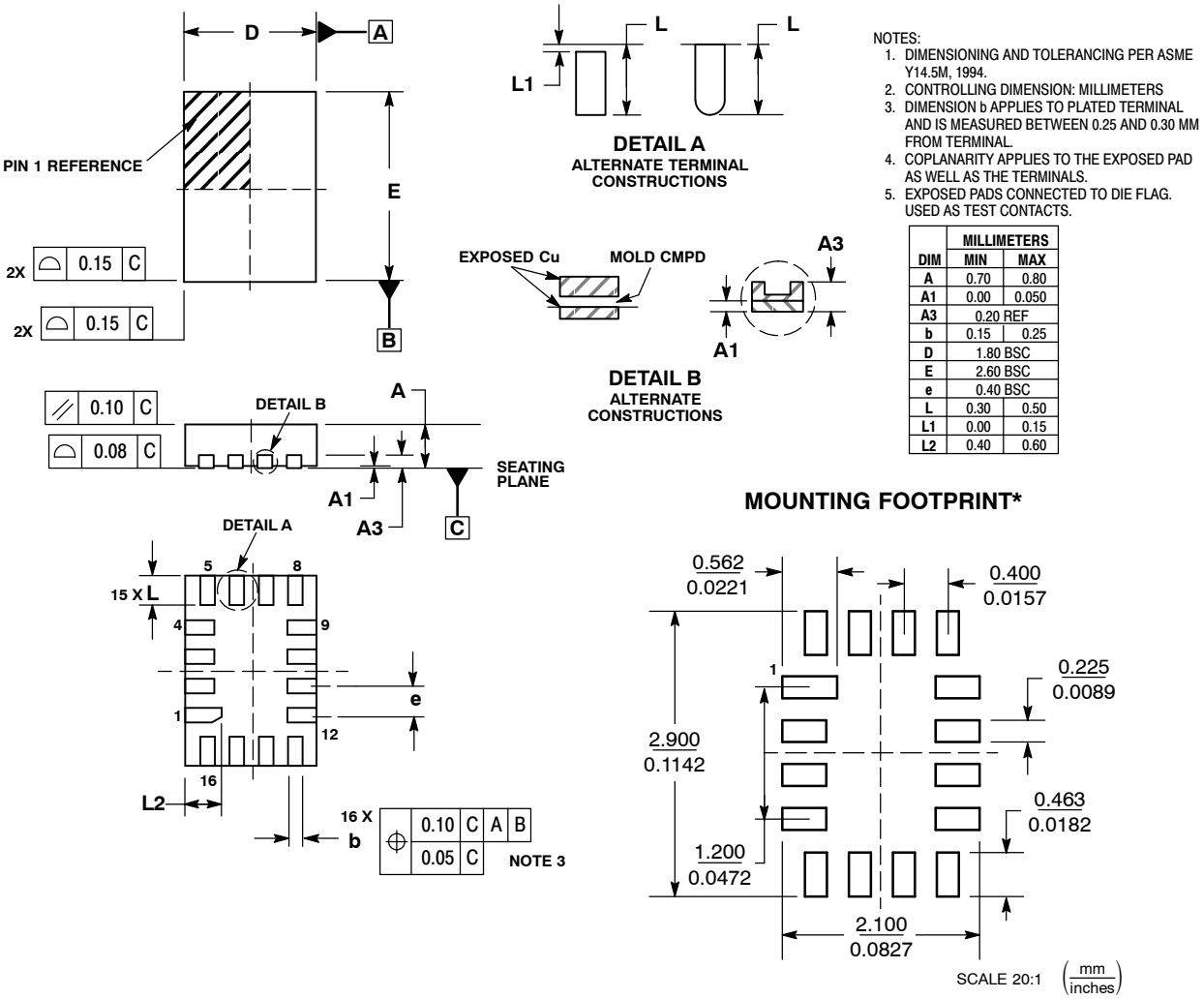
DEVICE ORDERING INFORMATION

Device Order Number	Device Nomenclature					Package Type	Tape & Reel Size†
	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix		
NLAS3799MNR2G	NL	AS	3799	MN	R2	WQFN (Pb−Free)	3000 / Tape & Reel
NLAS3799LMNR2G	NL	AS	3799L	MN	R2	WQFN (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

WQFN16, 1.8x2.6, 0.4P
CASE 488AP−01
ISSUE B



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
5. EXPOSED PADS CONNECTED TO DIE FLAG. USED AS TEST CONTACTS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.70	0.80
A1	0.00	0.050
A3	0.20 REF	
b	0.15	0.25
D	1.80 BSC	
E	2.60 BSC	
e	0.40 BSC	
L	0.30	0.50
L1	0.00	0.15
L2	0.40	0.60

MOUNTING FOOTPRINT*

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
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